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## Translating Bus Exchange Switch

## 7WBD383

The 7WBD383 is an advanced high-speed low-power translating bus exchange switch in ultra-small footprints.

## Features

- High Speed: $\mathrm{t}_{\mathrm{PD}}=0.25 \mathrm{~ns}(\mathrm{Max}) @ \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}$
- $3 \Omega$ Switch Connection Between 2 Ports
- Power Down Protection Provided on Inputs
- Zero Bounce
- TTL-Compatible Control Inputs
- Ultra-Small Pb-Free Packages
- These are $\mathrm{Pb}-$ Free Devices

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| AL, X, D383, AJ, AG | $=$ Specific Device Code |
| :--- | :--- |
| M | $=$ Date Code |
| A | $=$ Assembly Location |
| L | $=$ Lot Code |
| Y | $=$ Year Code |
| W | Week Code |
| - | Pb-Free Package |

(Note: Microdot may be in either location)
*Date Code orientation may vary depending upon manufacturing location.

## ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.


Figure 2. UQFN8
(Top Thru-View)

Figure 1. UDFN8
(Top Thru-View)


Figure 4. Logic Diagram

FUNCTION TABLE

| Input OE | Input EX | Function |
| :---: | :---: | :---: |
| L | L | $\mathrm{A}=\mathrm{C} ; \mathrm{B}=\mathrm{D}$ |
| L | H | $\mathrm{A}=\mathrm{D} ; \mathrm{B}=\mathrm{C}$ |
| H | X | Disconnect |

MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | DC Supply Voltage | -0.5 to +7.0 | V |
| $\mathrm{V}_{\text {IN }}$ | Control Pin Input Voltage | -0.5 to +7.0 | V |
| $\mathrm{V}_{1 / \mathrm{O}}$ | Switch Input / Output Voltage | -0.5 to +7.0 | V |
| $\mathrm{I}_{\mathrm{IK}}$ | Control Pin DC Input Diode Current $\quad \mathrm{V}_{\text {IN }}<\mathrm{GND}$ | -50 | mA |
| lok | Switch I/O Port DC Diode Current $\quad \mathrm{V}_{1 / \mathrm{O}}<$ GND | -50 | mA |
| Io | ON-State Switch Current | $\pm 128$ | mA |
|  | Continuous Current Through V ${ }_{\text {CC }}$ or GND | $\pm 150$ | mA |
| $\mathrm{I}_{\mathrm{CC}}$ | DC Supply Current Per Supply Pin | $\pm 150$ | mA |
| $\mathrm{I}_{\text {GND }}$ | DC Ground Current per Ground Pin | $\pm 150$ | mA |
| $\mathrm{T}_{\text {STG }}$ | Storage Temperature Range | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ | Lead Temperature, 1 mm from Case for 10 Seconds | 260 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{J}$ | Junction Temperature Under Bias | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\theta_{\text {JA }}$ | Thermal Resistance US8 (Note 1) <br>  UDFN8 <br> UQFN8  <br> Micro8  | $\begin{aligned} & \hline 251 \\ & 111 \\ & 208 \\ & 392 \end{aligned}$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{P}_{\mathrm{D}}$ | Power Dissipation in Still Air at $85^{\circ} \mathrm{C}$ US8 <br>  UDFN8 <br> UQFN8  <br> Micro8  | $\begin{gathered} \hline 498 \\ 1127 \\ 601 \\ 319 \end{gathered}$ | mW |
| MSL | Moisture Sensitivity | Level 1 |  |
| $\mathrm{F}_{\mathrm{R}}$ | Flammability Rating Oxygen Index: 28 to 34 | UL 94 V-0 @ 0.125 in |  |
| $\mathrm{V}_{\text {ESD }}$ | ESD Withstand VoltageHuman Body Mode (Note 2) <br> Machine Model (Note 3) <br> Charged Device Model (Note 4) | $\begin{gathered} >2000 \\ >200 \\ \text { N/A } \end{gathered}$ | V |
| ILATCHUP | Latchup Performance Above $\mathrm{V}_{\mathrm{CC}}$ and Below GND at $125^{\circ} \mathrm{C}$ (Note 5) | $\pm 200$ | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm -by-1 inch, 2 ounce copper trace no air flow.
2. Tested to EIA / JESD22-A114-A.
3. Tested to EIA / JESD22-A115-A.
4. Tested to JESD22-C101-A.
5. Tested to EIA / JESD78.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Positive DC Supply Voltage | 4.0 | 5.5 | V |
| $\mathrm{~V}_{\mathrm{IN}}$ | Control Pin Input Voltage | 0 | 5.5 | V |
| $\mathrm{~V}_{\mathrm{I} / \mathrm{O}}$ | Switch Input / Output Voltage | 0 | 5.5 | V |
| $\mathrm{~T}_{\mathrm{A}}$ | Operating Free-Air Temperature | -55 | +125 | ${ }^{\circ} \mathrm{C}$ |
| $\Delta \mathrm{t} / \Delta \mathrm{V}$ | Input Transition Rise or Fall Rate | Control Input <br> Switch $\mathrm{I} / \mathrm{O}$ | 0 | 5 |
|  |  | $\mathrm{nS} / \mathrm{V}$ |  |  |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Conditions | $\mathrm{V}_{\mathrm{cc}}$ <br> (V) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $\begin{gathered} T_{A}= \\ -55^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \end{gathered}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ | Max | Min | Max |  |
| $\mathrm{V}_{\mathrm{IK}}$ | Clamp Diode Voltage | $\mathrm{I}_{1 / \mathrm{O}}=-18 \mathrm{~mA}$ | 4.5 |  |  | -1.2 |  | -1.2 | V |
| $\mathrm{V}_{\mathrm{IH}}$ | High-Level Input Voltage (Control) |  | $\begin{gathered} 4.0 \text { to } \\ 5.5 \end{gathered}$ | 2.0 |  |  | 2.0 |  | V |
| $\mathrm{V}_{\mathrm{IL}}$ | Low-Level Input Voltage (Control) |  | $\begin{gathered} 4.0 \text { to } \\ 5.5 \end{gathered}$ |  |  | 0.8 |  | 0.8 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Voltage High | See Figure 5 |  |  |  |  |  |  |  |
| In | Input Leakage Current | $0 \leq \mathrm{V}_{\mathrm{IN}} \leq 5.5 \mathrm{~V}$ | 5.5 |  |  | $\pm 0.1$ |  | $\pm 1.0$ | $\mu \mathrm{A}$ |
| IOFF | Power Off Leakage Current | $\mathrm{V}_{1 / \mathrm{O}}=0$ to 5.5 V | 0 |  |  | $\pm 0.1$ |  | $\pm 1.0$ | $\mu \mathrm{A}$ |
| $I_{\text {cc }}$ | Quiescent Supply Current | $\begin{aligned} & \mathrm{I}_{\mathrm{O}}=0, \\ & \mathrm{~V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}} \text { or } 0 \mathrm{~V} \\ & \mathrm{OE}=\mathrm{GND} \\ & \mathrm{OE}=\mathrm{V}_{\mathrm{CC}} \end{aligned}$ | 5.5 |  |  | $\begin{aligned} & \pm 1.0 \\ & \pm 0.1 \end{aligned}$ |  | $\begin{aligned} & \pm 1.0 \\ & \pm 1.0 \end{aligned}$ | $\underset{\mu \mathrm{A}}{\mathrm{~mA}}$ |
| $\Delta \mathrm{l}$ CC | Increase in Supply Current (Control Pin) | One input at 3.4 V ; Other inputs at $\mathrm{V}_{\mathrm{CC}}$ or GND | 5.5 |  |  |  |  | 2.5 | mA |
| $\mathrm{R}_{\mathrm{ON}}$ | Switch ON Resistance | $\begin{aligned} & \mathrm{V}_{1 / O}=0, \\ & \mathrm{I}_{1 / \mathrm{O}}=64 \mathrm{~mA} \\ & \mathrm{I}_{/ O}=30 \mathrm{~mA} \end{aligned}$ | 4.5 |  | $\begin{aligned} & 3 \\ & 3 \end{aligned}$ | $\begin{aligned} & 7 \\ & 7 \end{aligned}$ |  | $\begin{aligned} & 7 \\ & 7 \end{aligned}$ | $\Omega$ |
|  |  | $\begin{aligned} & V_{1 / O}=2.4, \\ & I_{/ O}=15 \mathrm{~mA} \end{aligned}$ |  |  | 15 | 50 |  | 50 |  |
|  |  | $\begin{aligned} & V_{1 / 0}=2.4, \\ & I_{/ / O}=15 \mathrm{~mA} \end{aligned}$ | 4.0 |  | 50 | 70 |  | 70 |  |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test Condition | $\begin{aligned} & \mathrm{V}_{\mathrm{cc}} \\ & \text { (V) } \end{aligned}$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $\begin{gathered} \mathrm{T}_{\mathrm{A}}= \\ -55^{\circ} \mathrm{C} \text { to }+125^{\circ} \mathrm{C} \end{gathered}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ | Max | Min | Max |  |
| $t_{\text {PD }}$ | Propagation Delay, Bus to Bus | See Figure 6 | $\begin{gathered} 4.0 \text { to } \\ 5.5 \end{gathered}$ |  |  | 0.25 |  | 0.25 | ns |
| ${ }_{\text {tPD-EX }}$ | Propagation Delay, EX to Bus | See Figure 6 and Figure 7 | $\begin{gathered} 4.0 \text { to } \\ 5.5 \end{gathered}$ |  |  | 4.5 |  | 4.5 | ns |
| $t_{\text {EN }}$ | Output Enable Time | See Figure 6 | $\begin{gathered} 4.5 \text { to } \\ 5.5 \end{gathered}$ | 0.8 | 2.5 | 4.2 | 0.8 | 4.2 | ns |
|  |  |  | 4.0 | 0.8 | 3.0 | 4.6 | 0.8 | 4.6 |  |
| $\mathrm{t}_{\text {DIS }}$ | Output Disable Time |  | $\begin{gathered} 4.5 \text { to } \\ 5.5 \end{gathered}$ | 0.8 | 3.0 | 4.8 | 0.8 | 4.8 | ns |
|  |  |  | 4.0 | 0.8 | 2.9 | 4.4 | 0.8 | 4.4 |  |
| $\mathrm{C}_{\text {IN }}$ | Control Input Capacitance | $\mathrm{V}_{\mathrm{IN}}=5$ or 0 V | 5.0 |  | 2.5 |  |  |  | pF |
| $\mathrm{ClO}_{\text {(ON) }}$ | Switch On Capacitance | Switch ON | 5.0 |  | 10 |  |  |  | pF |
| $\mathrm{ClO}_{\text {(OFF) }}$ | Switch Off Capacitance | Switch OFF | 5.0 |  | 5 |  |  |  | pF |

TYPICAL DC CHARACTERISTICS




Figure 5. Output Voltage High vs Supply Voltage

## 7WBD383

## AC LOADING AND WAVEFORMS



| Test | S1 |
| :---: | :---: |
| $\mathrm{t}_{\mathrm{PD}}$ | Open |
| $\mathrm{t}_{\mathrm{PLZ}} / \mathrm{t}_{\mathrm{PZL}}$ | 7 V |
| $\mathrm{t}_{\mathrm{PHZ}} / \mathrm{t}_{\mathrm{PZH}}$ | Open |

${ }^{*} \mathrm{C}_{\mathrm{L}}$ includes probes and jig capacitance.


Voltage Waveforms Propagation Delay Times


Voltage Waveforms Enable and Disable Times
6. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control
7. All input pulses are supplied by generators having the following characteristics: PRR $\leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega, \mathrm{t}_{\mathrm{r}} \leq 2.5 \mathrm{~ns}, \mathrm{t}_{\mathrm{f}} \leq 2.5 \mathrm{~ns}$.
8. The outputs are measured one at a time, with one transition per measurement.
9. $t_{P L Z}$ and $t_{P H Z}$ are the same as $t_{\text {DIS }}$.
10. $\mathrm{t}_{\text {PLL }}$ and $\mathrm{t}_{\mathrm{PZH}}$ are the same as $\mathrm{t}_{\mathrm{EN}}$.
11. $\mathrm{t}_{\mathrm{PHL}}$ and $\mathrm{t}_{\mathrm{PLH}}$ are the same as $\mathrm{t}_{\mathrm{PD}}$.

Figure 6. $\mathrm{t}_{\mathrm{PD}}, \mathrm{t}_{\mathrm{EN}}, \mathrm{t}_{\mathrm{DIS}}$ Loading and Waveforms


Figure 7. tpD-EX Waveforms

## 7WBD383

ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :--- | :---: | :---: |
| 7WBD383USG | US88 <br> (Pb-Free) | $3000 /$ Tape \& Reel |
| 7WBD383MUTAG | UDFN8 <br> (Pb-Free) | $3000 /$ Tape \& Reel |
| 7WBD383AMUTCG | UQFN8 <br> (Pb-Free) | $3000 /$ Tape \& Reel |
| 7WBD383DMR2G | Micro8 <br> (Pb-Free) | $4000 /$ Tape \& Reel |
| 7WBD383DMUTCG | UDFN8, $1.95 \times 1.0,0.5 \mathrm{~mm}$ Pitch <br> (Pb-Free) | $3000 /$ Tape \& Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## PACKAGE DIMENSIONS

UDFN8 $1.8 \times 1.2,0.4 P$
CASE 517AJ
ISSUE O


$\rightarrow$ BOTTOM VIEW $\quad$| $\phi$ | 0.10 (M) | C | A | B |
| :--- | :--- | :--- | :--- | :--- |
|  | 0.05 (ㄴ) | C | NOTE 3 |  |

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS,
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM TERMINAL TIP.
4. MOLD FLASH ALLOWED ON TERMINALS ALONG EDGE OF PACKAGE. FLASH MAY ALONG EDGE OF PACKAGE. FLASH
NOT EXCEED 0.03 ONTO BOTTOM NOT EXCEED 0.03 ONTO BO
SURFACE OF TERMINALS.
5. DETAIL A SHOWS OPTIONAL CONSTRUCTION FOR TERMINALS.

|  | MILLIMETERS |  |  |
| :---: | :---: | :---: | :---: |
|  | DIMLIN | MIN |  |
| A | 0.45 | MAX |  |
| A1 | 0.00 | 0.05 |  |
| A3 | 0.127 | REF |  |
| b | 0.15 | 0.25 |  |
| b2 | 0.30 | REF |  |
| D | 1.80 | BSC |  |
| E | 1.20 BSC |  |  |
| e | 0.40 BSC |  |  |
| L | 0.45 | 0.55 |  |
| L1 | 0.00 | 0.03 |  |
| L2 | 0.40 | REF |  |

MOUNTING FOOTPRINT* SOLDERMASK DEFINED

*For additional information on our $\mathrm{Pb}-$ Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## PACKAGE DIMENSIONS

UDFN8 1.95x1.0, 0.5P
CASE 517CA
ISSUE A


NDTES:

1. DIMENSIDNING AND TQLERANCING PER ASME Y14.5M, 2009.
2. CUNTRDLLING DIMENSION: MILLIMETERS
3. DIMENSION $b$ APPLIES TD PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FRDM THE TERMINAL TIP.
CDPLANARITY APPLIES TD TD ALL THE TERMINALS
4. PACKAGE DIMENSIONS EXCLUSIVE DF BURRS AND MILD FLASH.


NDTE 4
SIDE VIEW


* For additional information on our Pb-Free strategy and soldering details, please download the ZN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

BDTtam VIEW NDTE 3

## PACKAGE DIMENSIONS

## UQFN8, 1.6x1.6, 0.5P

CASE 523AN
ISSUE O

*For additional information on our $\mathrm{Pb}-$ Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## 7WBD383

## PACKAGE DIMENSIONS

US8
CASE 493
ISSUE D

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## PACKAGE DIMENSIONS

Micro8<br>CASE 846A<br>ISSUE K



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